Am29LS18

Quad D Register with Standard and Three-State Outputs

DISTINCTIVE CHARACTERISTICS

- Low-power Schottky version of the popular Am2918
 Source standard tetam pole outputs
- Four three-state outputs
- Four standard totem-pole outputs
- Four D-type flip-flops
- GENERAL DESCRIPTION

The Am29LS18 consists of four D-type flip-flops with a buffered common clock. Information meeting the set-up and hold requirements on the D inputs is transferred to the Q outputs on the LOW-to-HIGH transition of the clock.

The same data as on the Q outputs is enabled at the threestate Y outputs when the "output control" (\overline{OE}) input is LOW. When the \overline{OE} input is HIGH, the Y outputs are in the high-impedance state.

The Am29LS18 is a 4-bit, high-speed register intended for use in real-time signal processing systems where the

standard outputs are used in a recursive algorithm and the three-state outputs provide access to a data bus to dump the results after a number of iterations.

The device can also be used as an address register or status register in computers or computer peripherals.

Likewise, the Am29LS18 is also useful in certain display applications where the standard outputs can be decoded to drive LED's (or equivalent) and the three-state outputs are bus organized for occasional interrogation of the data as displayed.





03623A Refer to Page 13-1 for Essential Information on Military Devices Am29LS18

PIN DESCRIPTION

Pin No.	Name	1/0	Description
	Di	1	The four data inputs to the register.
	Qi	0	The four data outputs of the register with standard totem-pole active pull-up outputs. Data is passed non-inverted
	Yi	0	The four three-state data outputs of the register. When the three-state outputs are enabled, data is passed non- inverted. A HIGH on the "output control" input forces the Yi outputs to the high-impedance state.
9	CP		CP Clock. The buffered common clock for the register. Enters data on the LOW-to-HIGH transition.
7	ŌĒ		\overline{OE} Output Control. When the \overline{OE} input is HIGH, the Y _i outputs are in the high-impedance state. When the \overline{OE} input is LOW, the TRUE register data is present at the Y _i outputs.

FUNCTION TABLE

	INPUTS		Ουτι		
ŌĒ	CLOCK CP	D	q	Y	NOTES
н	L	X	NC	Z	1
н	н	X	NC	Z Z Z Z	-
н	t	L	L	Z	-
н	t t	н	н	z	-
L	t t	L	L	L	-
L	t	н	н	н	-
L	_	-	Ļ	L	1
L	-	-	н	н	1
L = LC H = HI X = Dc		t =		nge HIGH t Ipedance	

Note: 1. When OE is LOW, the Y output will be in the same logic state as the Q output.



ABSOLUTE MAXIMUM RATINGS

OPERATING RANGES

Storage Temperature	Co
Supply Voltage to Ground Potential	
Continuous0.5V to +7.0V	Mil
DC Voltage Applied to Outputs For	1411
High Output State0.5V to +V _{CC} max	
DC Input Voltage0.5V to +7.0V	Op
DC Output Current, Into Outputs	alit
DC Input Current30mA to +5.0mA	and

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

Commercial (C) Devices	
Temperature	0°C to +70°C
Supply Voltage	+4.75V to +5.25V

lilitary (M) Devices

Temperature	55°C to +125°C
Supply Voltage	+ 4.5V to + 5.5V
Operating ranges define those limits o	ver which the function-
ality of the device is guaranteed.	

DC CHARACTERISTICS over operating range unless otherwise specified

Parameters	Description Test Conditions (Note 2)			Min	Typ (Note 1)	Max	Unite		
					MIL	2.5	3.4		
			Q, IOH 3	OH = - 660µA	COM'L	2.7	3.4		
VOH	Output HIGH Voltage	V _{CC} = MIN V _{IN} = V _{IH} or V _{IL}		MIL, IOH = -	1.0mA	2.4	3.4		Volts
			Y	COM'L, IOH	= 2.6mA	2.4	3.4		
				1 _{OL} = 4.0mA				0.4	
VOL	Output LOW Voltage	$V_{CC} = MIN$		t _{OL} = 8.0mA				0.45	Volts
		VIN = VIH or VIL		I _{OL} = 12mA				0.5	l
VIH	Input HiGH Level	Guaranteed input logical HIGH voltage for all inputs				2.0			Volts
	_	Guaranteed input logical LOW		MIL			0.7		
VIL	Input LOW Level			COM'L			0.8	Volts	
VI	Input Clamp Voltage	V _{CC} = MIN, I _{IN} =	– 18m.	A				- 1.5	Volts
ι _μ	Input LOW Current	V _{CC} = MAX, V _{IN}	$V_{CC} = MAX, V_{IN} = 0.4V$					-0.36	mA
цн.	Input HIGH Current	VCC - MAX, VIN	= 2.7V					20	μA
4	Input HIGH Current	V _{CC} = MAX, V _{IN} = 7.0V						0.1	mA
lo	Off-State (High-Impedance)	V _{CC} = MAX		$V_{\rm O} = 0.4V$ $V_{\rm O} = 2.4V$				-20	
	Output Current							20	μΑ
ISC	Output Short Circuit Current (Note 3)	V _{CC} = MAX			- 15		-85	mA	
łcc	Power Supply Current (Note 4)	V _{CC} = MAX				17	28	mA	

Notes: 1. Typical limits are at V_{CC} = 5.0V, 25°C ambient and maximum loading.
 2. For conditions shown as MIN or MAX, use the appropriate value specified under Operating Ranges for the applicable device type.
 3. Not more than one output should be shorted at a time. Duration of the short circuit test should not exceed one second.
 4. I_{CC} is measured with all inputs at 4.5V and all outputs open.

LOW-POWER SCHOTTKY INPUT/OUTPUT CURRENT INTERFACE CONDITIONS



Note: Actual current flow direction shown.

SWITCHING CHARACTERISTICS ($T_A = +25^{\circ}C$, $V_{CC} = 5.0V$)

Parameters	Description	Test Conditions	Min	Тур	Max	Units	
					18	27	ns
	- Clock to Qi			18	27] 115	
tPHL					18	27	
	Clock to Yi (OE LOW)				18	27	ns
tPHL		LOW	Ci = 15 oF	18	<u> </u>		<u> </u>
tpw	Clock Pulse Width	HIGH	C _L = 15 pF R _L = 2.0 kΩ	15	<u> </u>		ns
tg	Data			15	Ι		ns
th ć	Data			5.0			ns
					7.0	11	ns
tzH	- OE to Yi				8	12	
tzL	<u> </u>		C(=50 nE		14	21	
tHZ	OE to Yi		CL = 5.0 pF RL ≈ 2.0 kΩ		12	18	- ns
<u>trz</u>				35	50		MHz
fmax	Maximum Clock Frequency (Note 1)		design and the frequency				

Note 1. Per industry convention, fmax is the worst case value of the maximum device operating frequency with no constraints on tr, tr, pulse width or duty cycle.

SWITCHING CHARACTERISTICS over operating range unless otherwise specified*

·			COMMERCIAL Am29LS18		MILITARY Am29LS18		
Parameters	Description	Test Conditions	Min	Max	Min	Max	Units
				38		45	ns
	Clock to Qi			38		45	115
				35		40	ns
¹ РLН	Clock to Yi (OE LOW)			35		40	
tphL			20		20		ns
t _{pw}	Clock Pulse Width HIGH	C _L = 50 pF R _L = 2.0 kΩ	20		20		
t _s	Data		15		15		ns
ւ <u>s</u>	Data	-1	5.0		5.0		ns
		-		15		17	ns
12н	- OE to Y _i			16		17	
		$C_1 = 50 \text{ pF}$		27		30	
tHZ	- OE to Yi	C _L = 50 pF R _L = 2.0 kΩ		24		30	ns
tLZ fmax *AC performance of	Maximum Clock Frequency (Note 1)		30		25		MHz

*AC performance over the operating tempe

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